NSN 5961-01-557-1195

Diode Semiconductor Device - Page 1 of 1



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| Inclosure Material: |
|--|
| Plastic |
| Overall Length: |
| Between 0.140 inches and 0.152 inches |
| Overall Height: |
| Between 0.055 inches and 0.071 inches |
| Overall Width: |
| Between 0.037 inches and 0.053 inches |
| Semiconductor Material: |
| Silicon |
| Special Features: |
| Zener voltage - 4.09 to 4.52 v and 3.30 to 4.00 v; zener impedance - 90 ohms and 600 ohms; 500 mw rating; surface mount; corrosion |
| resistant finish; silicon |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| - |
| Demilitarization: |
| No |
| Fiig: |
| A110a0 |
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